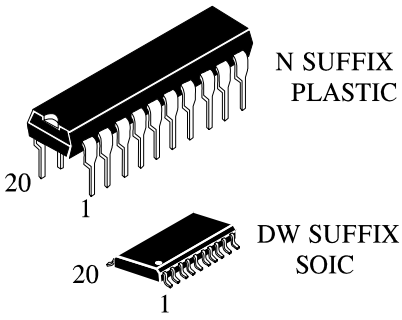
OCTAL 3-STATE INVERTING BUFFER/LINE DRIVER/LINE RECEIVER

High-Speed Silicon-Gate CMOS

The IN74ACT240 is identical in pinout to the LS/ALS240, HC/HCT240. The IN74ACT240 may be used as a level converter for interfacing TTL or NMOS outputs to High Speed CMOS inputs.

This octal inverting buffer/line driver/line receiver is designed to be used with 3-state memory address drivers, clock drivers, and other bus-oriented systems. The device has inverting outputs and two active-low output enables.

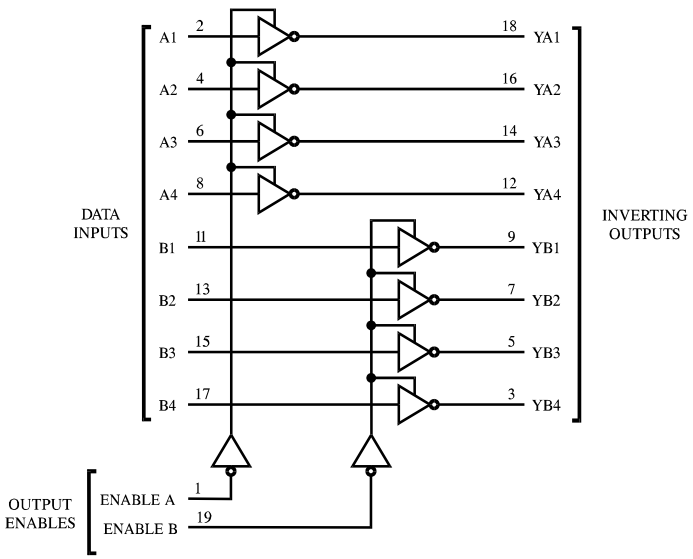
- TTL/NMOS Compatible Input Levels
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 4.5 to 5.5 V
- Low Input Current: 1.0 μA; 0.1 μA @ 25°C
- Outputs Source/Sink 24 mA



ORDERING INFORMATION

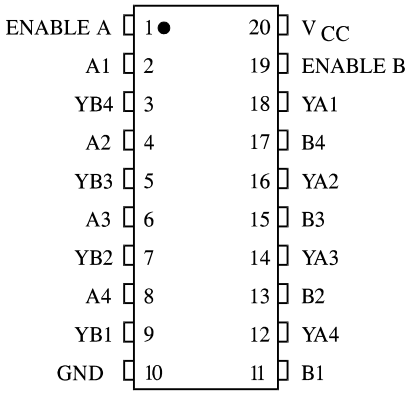
IN74ACT240N Plastic
IN74ACT240DW SOIC
T_A = -40° to 85° C for all packages

LOGIC DIAGRAM



PIN 20=V_{CC}
PIN 10 = GND

PIN ASSIGNMENT



FUNCTION TABLE

Inputs		Outputs
Enable A, Enable B	A,B	YA,YB
L	L	H
L	H	L
H	X	Z

X = don't care
Z = high impedance

INTEGRAL

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V_{IN}	DC Input Voltage (Referenced to GND)	-0.5 to V_{CC} +0.5	V
V_{OUT}	DC Output Voltage (Referenced to GND)	-0.5 to V_{CC} +0.5	V
I_{IN}	DC Input Current, per Pin	±20	mA
I_{OUT}	DC Output Sink/Source Current, per Pin	±50	mA
I_{CC}	DC Supply Current, V_{CC} and GND Pins	±50	mA
P_D	Power Dissipation in Still Air, Plastic DIP+ SOIC Package+	750 500	mW
Tstg	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package)	260	°C

*Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.
+Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C
SOIC Package: : - 7 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	4.5	5.5	V
V_{IN}, V_{OUT}	DC Input Voltage, Output Voltage (Referenced to GND)	0	V_{CC}	V
T_J	Junction Temperature (PDIP)		140	°C
T_A	Operating Temperature, All Package Types	-40	+85	°C
I_{OH}	Output Current - High		-24	mA
I_{OL}	Output Current - Low		24	mA
t_r, t_f	Input Rise and Fall Time * V_{CC} =4.5 V (except Schmitt Inputs) V_{CC} =5.5 V	0 0	10 8.0	ns/V

* V_{IN} from 0.8 V to 2.0 V

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range GND≤(V_{IN} or V_{OUT})≤V_{CC}.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS(Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V_{CC} V	Guaranteed Limits 25 °C	Guaranteed Limits -40°C to 85°C	Unit
V_{IH}	Minimum High-Level Input Voltage	V_{OUT}=0.1 V	4.5 5.5	2.0 2.0	2.0 2.0	V
V_{IL}	Maximum Low - Level Input Voltage	V_{OUT}= V_{CC}-0.1 V	4.5 5.5	0.8 0.8	0.8 0.8	V
V_{OH}	Minimum High-Level Output Voltage	$I_{OUT} \leq$ -50 μA	4.5 5.5	4.4 5.4	4.4 5.4	V
		*V_{IN}= V_{IL} I_{OH}=-24 mA I_{OH}=-24 mA	 4.5 5.5	 3.86 4.86	 3.76 4.76	
V_{OL}	Maximum Low-Level Output Voltage	$I_{OUT} \leq$ 50 μA	4.5 5.5	0.1 0.1	0.1 0.1	V
		*V_{IN}=V_{IH} I_{OL}=24 mA I_{OL}=24 mA	 4.5 5.5	 0.36 0.36	 0.44 0.44	
I_{IN}	Maximum Input Leakage Current	V_{IN}=V_{CC} or GND	5.5	±0.1	±1.0	μA
I_{OZ}	Maximum Three-State Leakage Current	V_{IN} (OE)=$V_{IL,}$ V_{IH} V_{IN}=V_{CC}, GND V_{OUT}=V_{CC}, GND	5.5	±0.5	±5.0	μA
ΔI_{CCT}	Additional Max I_{CC}/Input	V_{IN}=V_{CC} - 2.1 V	5.5		1.5	mA
I_{OLD}	+Minimum Dynamic Output Current	V_{OLD}=1.65 V Max	5.5		75	mA
I_{OHD}	+Minimum Dynamic Output Current	V_{OHD}=3.85 V Min	5.5		-75	mA
I_{CC}	Maximum Quiescent Supply Current (per Package)	V_{IN}=V_{CC} or GND	5.5	8.0	80	μA

* All outputs loaded; thresholds on input associated with output under test.
+Maximum test duration 2.0 ms, one output loaded at a time.

AC ELECTRICAL CHARACTERISTICS(V_{CC}=5.0 V ± 10%, C_L=50pF,Input t_r=t_f=3.0 ns)

Symbol	Parameter	Guaranteed Limits				Unit
		25 °C		-40°C to 85°C		
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay, A to YA or B to YB (Figure 1)	1.5	8.5	1.5	9.5	ns
t_{PHL}	Propagation Delay, A to YA or B to YB (Figure 1)	1.5	7.5	1.5	8.5	ns
t_{PZH}	Propagation Delay, Output Enable to YA or YB (Figure 2)	1.5	8.5	1.0	9.5	ns
t_{PZL}	Propagation Delay, Output Enable to YA or YB (Figure 2)	2.0	9.5	1.5	10.5	ns
t_{PHZ}	Propagation Delay, Output Enable to YA or YB (Figure 2)	2.0	9.5	2.0	10.5	ns
t_{PLZ}	Propagation Delay, Output Enable to YA or YB (Figure 2)	2.5	10.0	2.0	10.5	ns
C_{IN}	Maximum Input Capacitance	4.5		4.5		pF

		Typical @25°C,V_{CC}=5.0 V	
C_{PD}	Power Dissipation Capacitance	45	pF

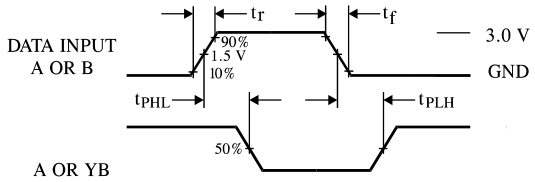


Figure 1. Switching Waveforms

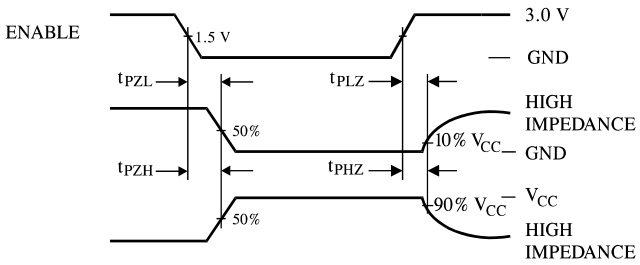


Figure 2. Switching Waveforms

INTEGRAL